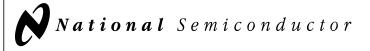
January 2000



# LM185-1.2/LM285-1.2/LM385-1.2 Micropower Voltage Reference Diode

## **General Description**

The LM185-1.2/LM285-1.2/LM385-1.2 are micropower 2-terminal band-gap voltage regulator diodes. Operating over a 10  $\mu$ A to 20 mA current range, they feature exceptionally low dynamic impedance and good temperature stability. On-chip trimming is used to provide tight voltage tolerance. Since the LM185-1.2 band-gap reference uses only transistors and resistors, low noise and good long term stability result.

Careful design of the LM185-1.2 has made the device exceptionally tolerant of capacitive loading, making it easy to use in almost any reference application. The wide dynamic operating range allows its use with widely varying supplies with excellent regulation.

The extremely low power drain of the LM185-1.2 makes it useful for micropower circuitry. This voltage reference can be used to make portable meters, regulators or general purpose analog circuitry with battery life approaching shelf life.

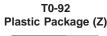
Further, the wide operating current allows it to replace older references with a tighter tolerance part.

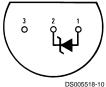
The LM185-1.2 is rated for operation over a -55°C to 125°C temperature range while the LM285-1.2 is rated -40°C to 85°C and the LM385-1.2 0°C to 70°C. The LM185-1.2/LM285-1.2 are available in a hermetic TO-46 package and the LM285-1.2/LM385-1.2 are also available in a low-cost TO-92 molded package, as well as SO and SOT-23. The LM185-1.2 is also available in a hermetic leadless chip carrier package.

### Features

- ±4 mV (±0.3%) max. initial tolerance (A grade)
- Operating current of 10 µA to 20 mA
- 0.6Ω max dynamic impedance (A grade)
- Low temperature coefficient
- Low voltage reference 1.235V
- 2.5V device and adjustable device also available
- LM185-2.5 series and LM185 series, respectively

# **Connection Diagrams**





Bottom View Order Number LM285Z-1.2, LM285BXZ-1.2, LM285BYZ-1.2 LM385Z-1.2, LM385BZ-1.2 LM385BXZ-1.2 or LM385BYZ-1.2 See NS Package Number Z03A



 $^{\ast}$  Pin 3 is attached to the Die Attach Pad (DAP) and should be connected to Pin 2 or left floating.

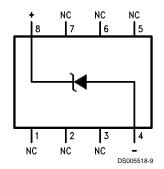
### Order Number LM385M3-1.2 See NS Package Number MA03B

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# LM185-1.2/LM285-1.2/LM385-1.2

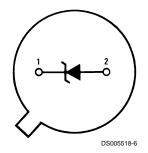
# Connection Diagrams (Continued)

SO Package



Order Number LM285M-1.2, LM285BXM-1.2, LM285BYM-1.2 LM385M-1.2, LM385BM-1.2 LM385BXM-1.2 or LM385BYM-1.2 See NS Package Number M08A

> TO-46 Metal Can Package (H)



Bottom View Order Number LM185H-1.2, LM185H-1.2/883, LM185BXH-1.2, LM185BYH-1.2 LM285H-1.2 or LM285BXH-1.2 See NS Package Number H02A

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# Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

(Note 2)

Reverse Current	30 mA
Forward Current	10 mA
Operating Temperature Range (Note 3)	
LM185-1.2	–55°C to +125°C
LM285-1.2	–40°C to +85°C
LM385-1.2	0°C to 70°C

# Electrical Characteristics (Note 4)

Storage Temperature	–55°C to +150°C
Soldering Information	
TO-92 package: 10 sec.	260°C
TO-46 package:10 sec.	300°C
SO and SOT Pkg.	
Vapor phase (60 sec.)	215°C
Infrared (15 sec.)	220°C
See AN-450 "Surface Mounting Metho on Product Reliability" for other metho surface mount devices.	ods and Their Effect ods of soldering

Parameter	Conditions	Тур	LM185-1.2 LM185BX-1.2 LM185BY-1.2 LM285-1.2 LM285BX-1.2 LM285BX-1.2 LM285BY-1.2 Tested Design		LM385B-1.2 LM385BX-1.2 LM385BY-1.2 Tested Design		LM385-1.2 Tested Design		Units (Limit)
			Limit	Limit	Limit	Limit	Limit	Limit	
			(Notes 5, 8)	(Note 6)	(Note 5)	(Note 6)	(Note 5)	(Note 6)	
Reverse Breakdown	T <sub>A</sub> = 25°C,	1.235	1.223		1.223		1.205		V(Min)
Voltage	$10 \ \mu A \le I_R \le 20 \ mA$		1.247		1.247		1.260		V(Max)
Minimum Operating		8	10	20	15	20	15	20	μA
Current	LM385M3-1.2						10	15	(Max)
Reverse Breakdown Voltage Change	$10 \ \mu A \le I_R \le 1 \ mA$		1	1.5	1	1.5	1	1.5	mV (Max)
with Current	$1 \text{ mA} \leq I_R \leq 20 \text{ mA}$		10	20	20	25	20	25	mV (Max)
Reverse Dynamic Impedance	I <sub>R</sub> = 100 μA, f = 20 Hz	1							Ω
Wideband Noise (rms)	$I_R = 100 \ \mu A,$ 10 Hz $\leq f \leq 10 \ kHz$	60							μV
Long Term Stability	$I_R = 100 \ \mu A, T = 1000 \ Hr,$ $T_A = 25^{\circ}C \pm 0.1^{\circ}C$	20							ppm
Average Temperature	I <sub>R</sub> = 100 μA								
Coefficient (Note 7)	X Suffix		30		30				ppm/°C
	Y Suffix		50		50				ppm/°C
	All Others			150		150		150	ppm/°C (Max)

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed.

Note 2: Refer to RETS185H-1.2 for military specifications.

**Note 3:** For elevated temperature operation, T<sub>i</sub> max is:

LM185 150°C

LM285 125°C

LM385 100°C

Thermal Resistance	TO-92	TO-46	SO-8	SOT23
$\theta_{JA}$ (junction to ambient)	180°C/W (0.4" leads)	440°C/W	165°C/W	283°C/W
	170°C/W (0.125" leads)			
$\theta_{JC}$ (junction to case)	N/A	80°C/W	N/A	N/A

Note 4: Parameters identified with boldface type apply at temperature extremes. All other numbers apply at  $T_A = T_J = 25$  °C.

3

# Electrical Characteristics (Note 4) (Continued)

Note 5: Guaranteed and 100% production tested.

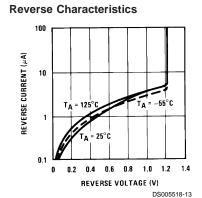
Note 6: Guaranteed, but not 100% production tested. These limits are not used to calculate average outgoing quality levels.

Note 7: The average temperature coefficient is defined as the maximum deviation of reference voltage at all measured temperatures between the operating  $T_{MAX}$  and  $T_{MIN}$ , divided by  $T_{MAX} - T_{MIN}$ . The measured temperatures are -55°C, -40°C, 0°C, 25°C, 70°C, 85°C, 125°C.

**Reverse Characteristics** 

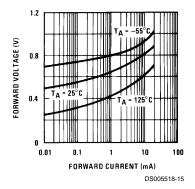
Note 8: A military RETS electrical specification is available on request.

# **Typical Performance Characteristics**

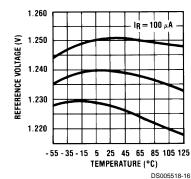


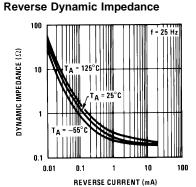
# (10)

**Forward Characteristics** 



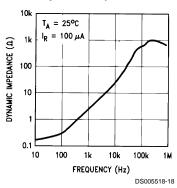
Temperature Drift of 3 Representative Units



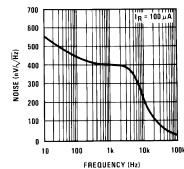


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**Reverse Dynamic Impedance** 

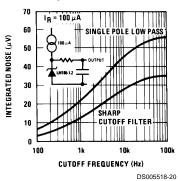




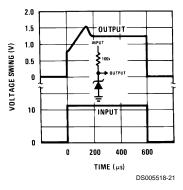


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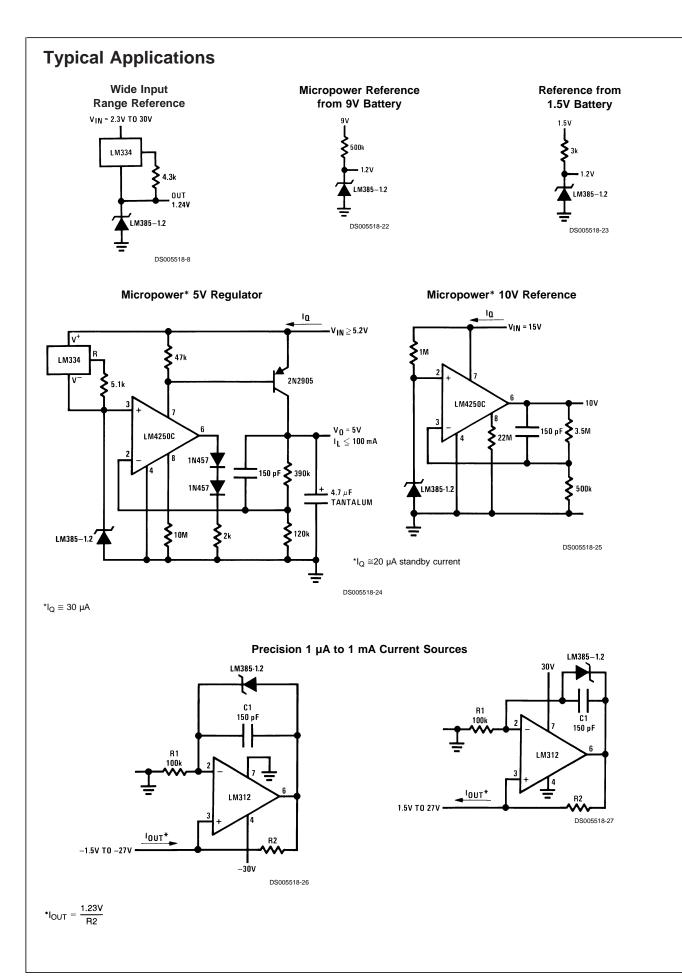
Filtered Output Noise





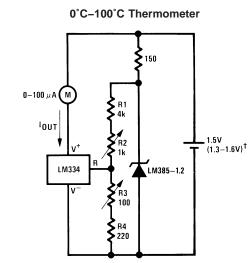


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# LM185-1.2/LM285-1.2/LM385-1.2

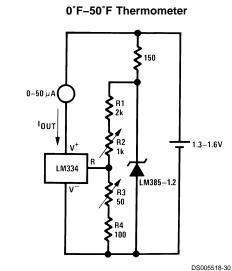
# Typical Applications (Continued)



DS005518-28

#### Calibration

1. Short LM385-1.2, adjust R3 for I<sub>OUT</sub>= temp at 1 µA/°K 2. Remove short, adjust R2 for correct reading in centigrade †I<sub>Q</sub> at 1.3V≅500 μA I<sub>Q</sub> at 1.6V≅2.4 mA



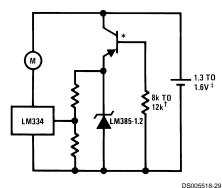
#### Calibration

1. Short LM385-1.2, adjust R3 for  $I_{OUT}\text{=}$  temp at 1.8  $\mu\text{A/}^{\circ}\text{K}$ 

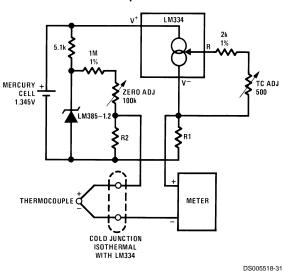
2. Remove short, adjust R2 for correct reading in °F

### METER THERMOMETERS





\*2N3638 or 2N2907 select for inverse  $H_{FE} \cong 5$ †Select for operation at 1.3V  $\ddagger I_Q \cong 600 \ \mu A$  to 900  $\mu A$ 



### **Micropower Thermocouple Cold Junction** Compensator

**Adjustment Procedure** 

1. Adjust TC ADJ pot until voltage across R1 equals Kelvin temperature multiplied by the thermocouple Seebeck coefficient.

2. Adjust zero ADJ pot until voltage across R2 equals the thermocouple Seebeck coefficient multiplied by 273.2.

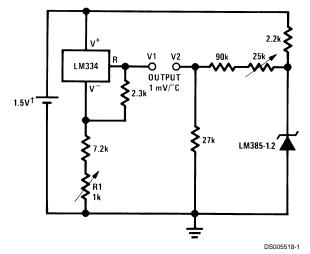
Thermocouple	Seebeck	R1	R2	Voltage	Voltage
Туре	Coefficient	<b>(</b> Ω <b>)</b>	<b>(</b> Ω <b>)</b>	Across R1	Across R2
	(µV/°C)			@ 25°C	(mV)
				(mV)	
J	52.3	523 1	1.24k	15.60	14.32
т	42.8	432	1k	12.77	11.78
к	40.8	412 9	953Ω	12.17	11.17
S	6.4	63.4 1	150Ω	1.908	1.766

Typical supply current 50 µA

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# Typical Applications (Continued)

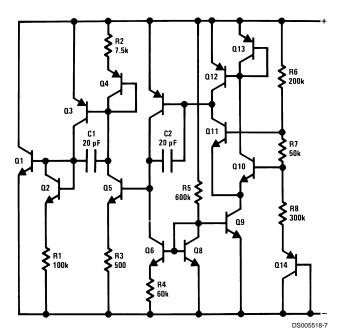
Centigrade Thermometer

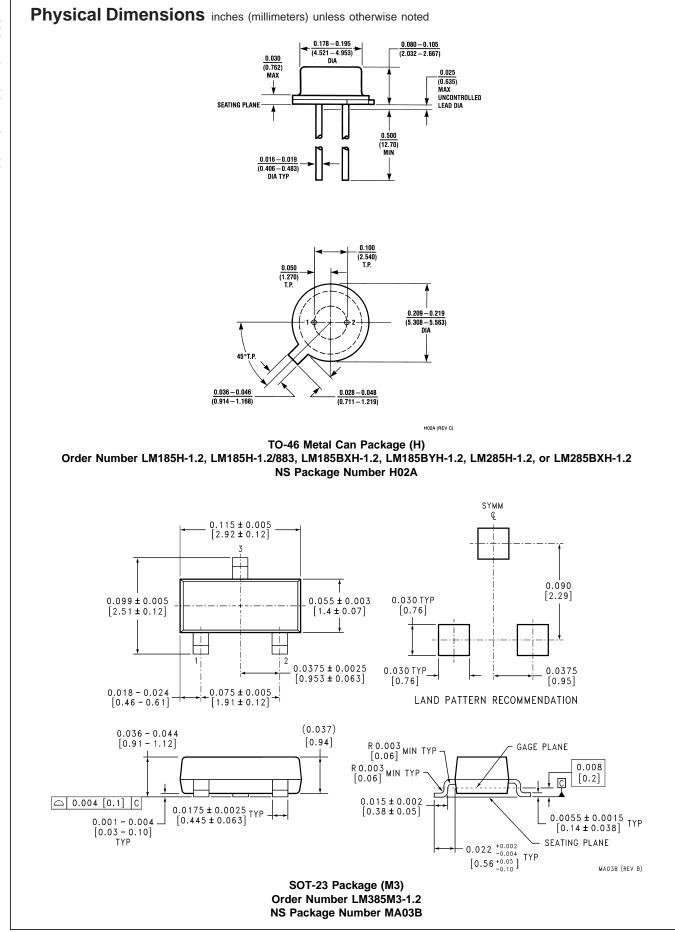


### Calibration

1. Adjust R1 so that V1 = temp at 1 mV/\*K 2. Adjust V2 to 273.2 mV †I<sub>Q</sub> for 1.3V to 1.6V battery voltage = 50  $\mu$ A to 150  $\mu$ A

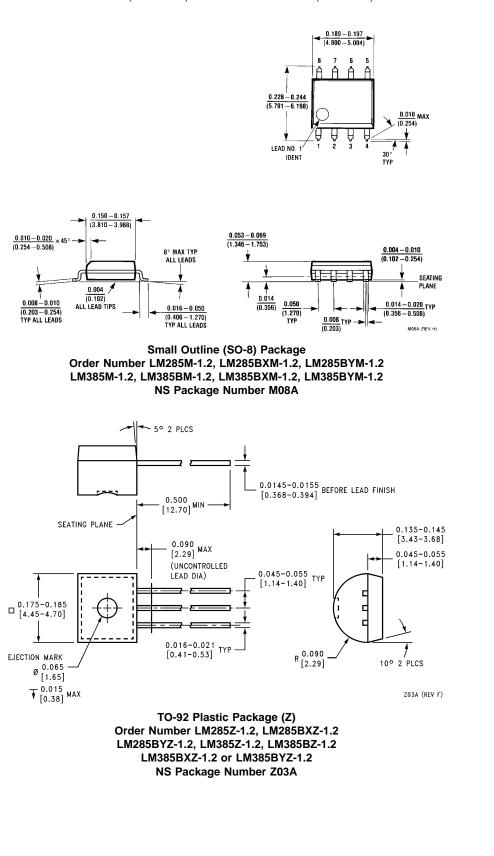
# **Schematic Diagram**





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Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



### Notes

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